

1,048,576 WORD $\times$ 4 BIT DYNAMIC RAM

PRELIMINARY

DESCRIPTION

The TC514400APL/AJL/ASJL/AZL is the new generation dynamic RAM organized 1,048,576 words by 4 bits. The TC514400APL/AJL/ASJL/AZL utilizes TOSHIBA's CMOS Silicon gate process technology as well as advanced circuit techniques to provide wide operating margins, both internally and to the system user. Multiplexed address inputs permit the TC514400APL/AJL/ASJL/AZL to be packaged in a standard 20 pin plastic DIP, 26/20 pin plastic SOJ (300/350mil) and 20 pin plastic ZIP. The package size provides high system bit densities and is compatible with widely available automated testing and insertion equipment. System oriented features include single power supply of $5V \pm 10\%$ tolerance, direct interfacing capability with high performance logic families such as Schottky TTL.

FEATURES

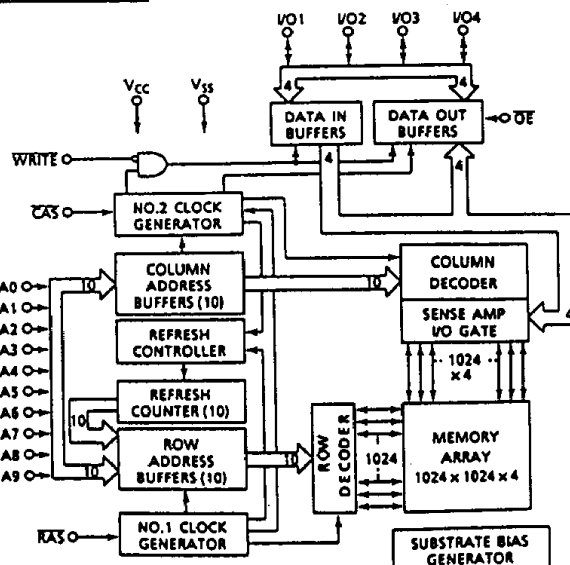
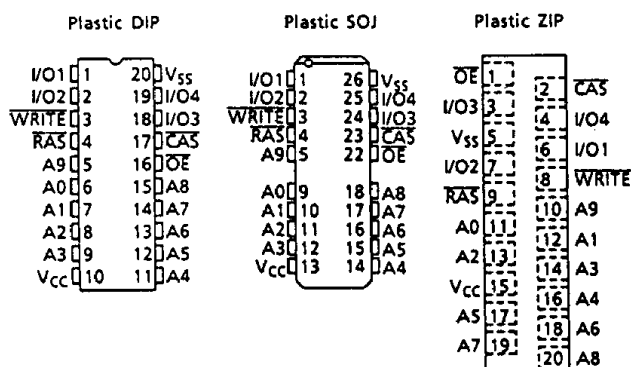
- 1,048,576 word by 4 bit organization
- Fast access time and cycle time
- Low Power
 - 550mW MAX. Operating (TC514400APL/AJL/ASJL/AZL-70)
 - 468mW MAX. Operating (TC514400APL/AJL/ASJL/AZL-80)
 - 413mW MAX. Operating (TC514400APL/AJL/ASJL/AZL-10)
 - 1.1mW MAX. Standby
- Outputs unlatched at cycle end allows two-dimensional chip selection
- Read-Modify-Write, CAS before RAS refresh, RAS-only refresh, Hidden refresh, and Fast Page Mode and Test Mode capability
- All inputs and outputs TTL compatible
- 1024 refresh cycles/128ms
- Package
 - TC514400APL : DIP20-P-300C
 - TC514400AJL : SOJ26-P-350
 - TC514400ASJL : SOJ26-P-300A
 - TC514400AZL : ZIP20-P-400A

PIN NAMES

A0~A9	Address Inputs	OE	Output Enable
RAS	Row Address Strobe	I/O1~I/O4	Data Input/Output
CAS	Column Address Strobe	V _{CC}	Power (+5V)
WRITE	Read/Write Input	V _{SS}	Ground

BLOCK DIAGRAM

PIN CONNECTION (TOP VIEW)



TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

ABSOLUTE MAXIMUM RATINGS

ITEM	SYMBOL	RATING	UNITS	NOTES
Input Voltage	V_{IN}	-1~7	V	1
Output Voltage	V_{OUT}	-1~7	V	1
Power Supply Voltage	V_{CC}	-1~7	V	1
Operating Temperature	T_{OPR}	0~70	°C	1
Storage Temperature	T_{STG}	-55~150	°C	1
Soldering Temperature - Time	T_{SOLDER}	260 - 10	°C - sec	1
Power Dissipation	P_D	700	mW	1
Short Circuit Output Current	I_{OUT}	50	mA	1

RECOMMENDED DC OPERATING CONDITIONS ($T_a = 0 \sim 70^\circ\text{C}$)

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT	NOTES
V_{CC}	Supply Voltage	4.5	5.0	5.5	V	2
V_{IH}	Input High Voltage	2.4	-	6.5	V	2
V_{IL}	Input Low Voltage	-1.0	-	0.8	V	2

TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

DC ELECTRICAL CHARACTERISTICS ($V_{CC} = 5V \pm 10\%$, $T_a = 0 \sim 70^\circ C$)

SYMBOL	PARAMETER	MIN.	MAX.	UNITS	NOTES
I_{CC1}	OPERATING CURRENT	TC514400APL/AJL/ASJL/AZL-70	-	100	mA 3, 4 5
	Average Power Supply Operating Current ($\overline{RAS}$, $\overline{CAS}$, Address Cycling: $t_{RC} = t_{RC} \text{ MIN.}$)	TC514400APL/AJL/ASJL/AZL-80	-	85	
		TC514400APL/AJL/ASJL/AZL-10	-	75	
I_{CC2}	STANDBY CURRENT Power Supply Standby Current ($\overline{RAS} = \overline{CAS} = V_{IH}$)	-	2	mA	
I_{CC3}	$\overline{RAS}$ ONLY REFRESH CURRENT	TC514400APL/AJL/ASJL/AZL-70	-	100	mA 3, 5
	Average Power Supply Current, $\overline{RAS}$ Only Mode ($\overline{RAS}$ Cycling, $\overline{CAS} = V_{IH}$: $t_{RC} = t_{RC} \text{ MIN.}$)	TC514400APL/AJL/ASJL/AZL-80	-	85	
		TC514400APL/AJL/ASJL/AZL-10	-	75	
I_{CC4}	FAST PAGE MODE CURRENT	TC514400APL/AJL/ASJL/AZL-70	-	70	mA 3, 4 5
	Average Power Supply Current, Fast Page Mode ($\overline{RAS} = V_{IL}$, $\overline{CAS}$, Address Cycling: $t_{PC} = t_{PC} \text{ MIN.}$)	TC514400APL/AJL/ASJL/AZL-80	-	60	
		TC514400APL/AJL/ASJL/AZL-10	-	55	
I_{CC5}	STANDBY CURRENT Power Supply Standby Current ($\overline{RAS} = \overline{CAS} = V_{CC} - 0.2V$)	-	200	μA	
I_{CC6}	$\overline{CAS}$ BEFORE $\overline{RAS}$ REFRESH CURRENT	TC514400APL/AJL/ASJL/AZL-70	-	100	mA 3, 5
	Average Power Supply Current, $\overline{CAS}$ Before $\overline{RAS}$ Mode ($\overline{RAS}$, $\overline{CAS}$ Cycling: $t_{RC} = t_{RC} \text{ MIN.}$)	TC514400APL/AJL/ASJL/AZL-80	-	85	
		TC514400APL/AJL/ASJL/AZL-10	-	75	
I_{CC7}	Battery Back Up Current Average Power Supply Current, Battery Back Up Mode ($\overline{CAS} = \overline{CAS}$ Before $\overline{RAS}$ Cycling or 0.2V, $\overline{OE} = V_{CC} - 0.2V$, $\overline{WRITE} = V_{CC} - 0.2V$, $A0 \sim 9 = V_{CC} - 0.2V$ or 0.2V, $VO1 \sim 4 = V_{CC} - 0.2V$, 0.2V or OPEN: $t_{RC} = 125\mu s$, $t_{RAS} = 300ns \sim 1\mu s$)	-	400	μA	3, 6
I_{CC7}	Battery Back Up Current Average Power Supply Current, Battery Back Up Mode ($\overline{CAS} = \overline{CAS}$ Before $\overline{RAS}$ Cycling or 0.2V, $\overline{OE} = V_{CC} - 0.2V$, $\overline{WRITE} = V_{CC} - 0.2V$, $A0 \sim 9 = V_{CC} - 0.2V$ or 0.2V, $VO1 \sim 4 = V_{CC} - 0.2V$, 0.2V or OPEN: $t_{RC} = 125\mu s$, $t_{RAS} = t_{RAS} \text{ MIN.} \sim 300ns$)	-	300	μA	3, 6
$I_{I(L)}$	INPUT LEAKAGE CURRENT Input Leakage Current, any input ($0V \leq V_{IN} \leq 6.5V$, All Other Pins Not Under Test = 0V)	-10	10	μA	
$I_{O(L)}$	OUTPUT LEAKAGE CURRENT (D_{OUT} is disabled, $0V \leq V_{OUT} \leq 5.5V$)	-10	10	μA	
V_{OH}	OUTPUT LEVEL Output "H" Level Voltage ($I_{OUT} = -5mA$)	2.4	-	V	
V_{OL}	OUTPUT LEVEL Output "L" Level Voltage ($I_{OUT} = 4.2mA$)	-	0.4	V	

TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

ELECTRICAL CHARACTERISTICS AND RECOMMENDED AC OPERATING CONDITIONS

($V_{CC} = 5V \pm 10\%$, $T_a = 0 \sim 70^\circ C$) (Notes 7, 8, 9)

SYMBOL	PARAMETER	TC514400APL/ AJL/ASJL/AZL-70		TC514400APL/ AJL/ASJL/AZL-80		TC514400APL/ AJL/ASJL/AZL-10		UNIT	NOTES
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
t_{RC}	Random Read or Write Cycle Time	130	—	150	—	180	—	ns	
t_{RMW}	Read-Modify-Write Cycle Time	185	—	205	—	245	—	ns	
t_{PC}	Fast Page Mode Cycle Time	45	—	50	—	60	—	ns	
t_{PRMW}	Fast Page Mode Read-Modify-Write Cycle Time	100	—	105	—	125	—	ns	
t_{RAC}	Access Time from $\overline{RAS}$	—	70	—	80	—	100	ns	10,15 16
t_{CAC}	Access Time from $\overline{CAS}$	—	20	—	20	—	25	ns	10,15
t_{AA}	Access Time from Column Address	—	35	—	40	—	50	ns	10,16
t_{CPA}	Access Time from $\overline{CAS}$ Precharge	—	40	—	45	—	55	ns	10
t_{CLZ}	$\overline{CAS}$ to output in Low-Z	0	—	0	—	0	—	ns	10
t_{OFF}	Output Buffer Turn-off Delay	0	20	0	20	0	20	ns	11
t_T	Transition Time (Rise and Fall)	3	50	3	50	3	50	ns	9
t_{RP}	$\overline{RAS}$ Precharge Time	50	—	60	—	70	—	ns	
t_{RAS}	$\overline{RAS}$ Pulse Width	70	10,000	80	10,000	100	10,000	ns	
t_{RASP}	$\overline{RAS}$ Pulse Width (Fast Page Mode)	70	200,000	80	200,000	100	200,000	ns	
t_{RSH}	$\overline{RAS}$ Hold Time	20	—	20	—	25	—	ns	
t_{RHCP}	$\overline{RAS}$ Hold Time From $\overline{CAS}$ Precharge (Fast Page Mode)	40	—	45	—	55	—	ns	
t_{CSH}	$\overline{CAS}$ Hold Time	70	—	80	—	100	—	ns	
t_{CAS}	$\overline{CAS}$ Pulse Width	20	10,000	20	10,000	25	10,000	ns	
t_{RCD}	$\overline{RAS}$ to $\overline{CAS}$ Delay Time	20	50	20	60	25	75	ns	15
t_{RAD}	$\overline{RAS}$ to Column Address Delay Time	15	35	15	40	20	50	ns	16
t_{CRP}	$\overline{CAS}$ to $\overline{RAS}$ Precharge Time	5	—	5	—	5	—	ns	
t_{CP}	$\overline{CAS}$ Precharge Time	10	—	10	—	10	—	ns	
t_{ASR}	Row Address Set-Up Time	0	—	0	—	0	—	ns	
t_{RAH}	Row Address Hold Time	10	—	10	—	15	—	ns	
t_{ASC}	Column Address Set-Up Time	0	—	0	—	0	—	ns	
t_{CAH}	Column Address Hold Time	15	—	15	—	20	—	ns	
t_{RAL}	Column Address to $\overline{RAS}$ Lead Time	35	—	40	—	50	—	ns	
t_{RCS}	Read Command Set-Up Time	0	—	0	—	0	—	ns	
t_{RCH}	Read Command Hold Time	0	—	0	—	0	—	ns	12

TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

ELECTRICAL CHARACTERISTICS AND RECOMMENDED AC OPERATING CONDITIONS (Continued)

SYMBOL	PARAMETER	TC514400APL/ AJL/ASJL/AZL-70		TC514400APL/ AJL/ASJL/AZL-80		TC514400APL/ AJL/ASJL/AZL-10		UNITS	NOTES
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
t_{RRH}	Read Command Hold Time referenced to $\overline{RAS}$	0	-	0	-	0	-	ns	12
t_{WCH}	Write Command Hold Time	15	-	15	-	20	-	ns	
t_{WP}	Write Command Pulse Width	15	-	15	-	20	-	ns	
t_{RWL}	Write Command to $\overline{RAS}$ Lead Time	20	-	20	-	25	-	ns	
t_{CWL}	Write Command to $\overline{CAS}$ Lead Time	20	-	20	-	25	-	ns	
t_{DS}	Data Set-Up Time	0	-	0	-	0	-	ns	13
t_{DH}	Data Hold Time	15	-	15	-	20	-	ns	13
t_{REF}	Refresh Period	-	128	-	128	-	128	ms	
t_{WCS}	Write Command Set-Up Time	0	-	0	-	0	-	ns	14
t_{CWD}	$\overline{CAS}$ to $\overline{WRITE}$ Delay Time	50	-	50	-	60	-	ns	14
t_{RWD}	$\overline{RAS}$ to $\overline{WRITE}$ Delay Time	100	-	110	-	135	-	ns	14
t_{AWD}	Column Address to $\overline{WRITE}$ Delay Time	65	-	70	-	85	-	ns	14
t_{CPWD}	$\overline{CAS}$ Precharge to $\overline{WRITE}$ Delay Time	70	-	75	-	90	-	ns	14
t_{CSR}	$\overline{CAS}$ Set-Up Time ($\overline{CAS}$ before $\overline{RAS}$ Cycle)	5	-	5	-	5	-	ns	
t_{CHR}	$\overline{CAS}$ Hold Time ($\overline{CAS}$ before $\overline{RAS}$ Cycle)	15	-	15	-	20	-	ns	
t_{RPC}	$\overline{RAS}$ to $\overline{CAS}$ Precharge Time	0	-	0	-	0	-	ns	
t_{CPT}	$\overline{CAS}$ Precharge Time ($\overline{CAS}$ before $\overline{RAS}$ Counter Test Cycle)	40	-	40	-	50	-	ns	
t_{ROH}	$\overline{RAS}$ Hold Time referenced to $\overline{OE}$	10	-	10	-	20	-	ns	
t_{OEA}	$\overline{OE}$ Access Time	-	20	-	20	-	25	ns	
t_{OED}	$\overline{OE}$ to Data Delay	20	-	20	-	25	-	ns	
t_{OEZ}	Output buffer turn off Delay Time from $\overline{OE}$	0	20	0	20	0	20	ns	10
t_{OEH}	$\overline{OE}$ Command Hold Time	20	-	20	-	25	-	ns	
t_{WTS}	Write Command Set-Up Time (Test Mode In)	10	-	10	-	10	-	ns	
t_{WTH}	Write Command Hold Time (Test Mode In)	10	-	10	-	10	-	ns	
t_{WRP}	$\overline{WRITE}$ to $\overline{RAS}$ Precharge Time ($\overline{CAS}$ before $\overline{RAS}$ Cycle)	10	-	10	-	10	-	ns	
t_{WRH}	$\overline{WRITE}$ to $\overline{RAS}$ Hold Time ($\overline{CAS}$ before $\overline{RAS}$ Cycle)	10	-	10	-	10	-	ns	

TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

ELECTRICAL CHARACTERISTICS AND RECOMMENDED AC OPERATING CONDITIONS IN THE TEST MODE

SYMBOL	PARAMETER	TC514400APL/ AJL/ASJL/AZL-70		TC514400APL/ AJL/ASJL/AZL-80		TC514400APL/ AJL/ASJL/AZL-10		UNITS	NOTES
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
t _{RC}	Random Read or Write Cycle Time	135	—	155	—	185	—	ns	
t _{RMW}	Read-Modify-Write Cycle Time	190	—	210	—	250	—	ns	
t _{PC}	Fast Page Mode Cycle Time	50	—	55	—	65	—	ns	
t _{RMR}	Fast Page Mode Read-Modify-Write Cycle Time	190	—	210	—	250	—	ns	
t _{RAC}	Access Time from $\overline{RAS}$	—	75	—	85	—	105	ns	10,15 16
t _{CAC}	Access Time from $\overline{CAS}$	—	25	—	25	—	30	ns	9,15
t _{AA}	Access Time from Column Address	—	40	—	45	—	55	ns	9,16
t _{CPA}	Access Time from $\overline{CAS}$ Precharge	—	40	—	50	—	60	ns	10
t _{RAS}	$\overline{RAS}$ Pulse Width	75	10,000	85	10,000	105	10,000	ns	
t _{RASP}	$\overline{RAS}$ Pulse Width (Fast Page Mode)	75	100,000	85	200,000	105	200,000	ns	
t _{RSH}	$\overline{RAS}$ Hold Time	25	—	25	—	30	—	ns	
t _{CSH}	$\overline{CAS}$ Hold Time	75	—	85	—	105	—	ns	
t _{RHCP}	$\overline{CAS}$ Precharge to $\overline{RAS}$ Hold Time	45	—	55	—	65	—	ns	
t _{CAS}	$\overline{CAS}$ Pulse Width	25	10,000	25	10,000	30	10,000	ns	
t _{RAL}	Column Address to $\overline{RAS}$ Lead Time	40	—	45	—	55	—	ns	
t _{CWD}	$\overline{CAS}$ to $\overline{WRITE}$ Delay Time	55	—	55	—	65	—	ns	14
t _{RWd}	$\overline{RAS}$ to $\overline{WRITE}$ Delay Time	105	—	115	—	140	—	ns	14
t _{AWd}	Column Address to $\overline{WRITE}$ Delay Time	70	—	75	—	90	—	ns	14
t _{CPWD}	$\overline{CAS}$ Precharge to $\overline{WRITE}$ Delay Time	75	—	80	—	95	—	ns	14
t _{OEa}	$\overline{OE}$ Access Time from	—	25	—	25	—	30	ns	
t _{OEh}	$\overline{OE}$ Command Hold Time	25	—	25	—	30	—	ns	

CAPACITANCE ($V_{CC} = 5V \pm 10\%$, $f = 1MHz$, $T_a = 0 \sim 70^\circ C$)

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
C _{I1}	Input Capacitance (A0~A9)	—	5	pF
C _{I2}	Input Capacitance ($\overline{RAS}$, $\overline{CAS}$, $\overline{WRITE}$, $\overline{OE}$)	—	7	pF
C _O	Input/Output Capacitance (I/O1~I/O4)	—	7	pF

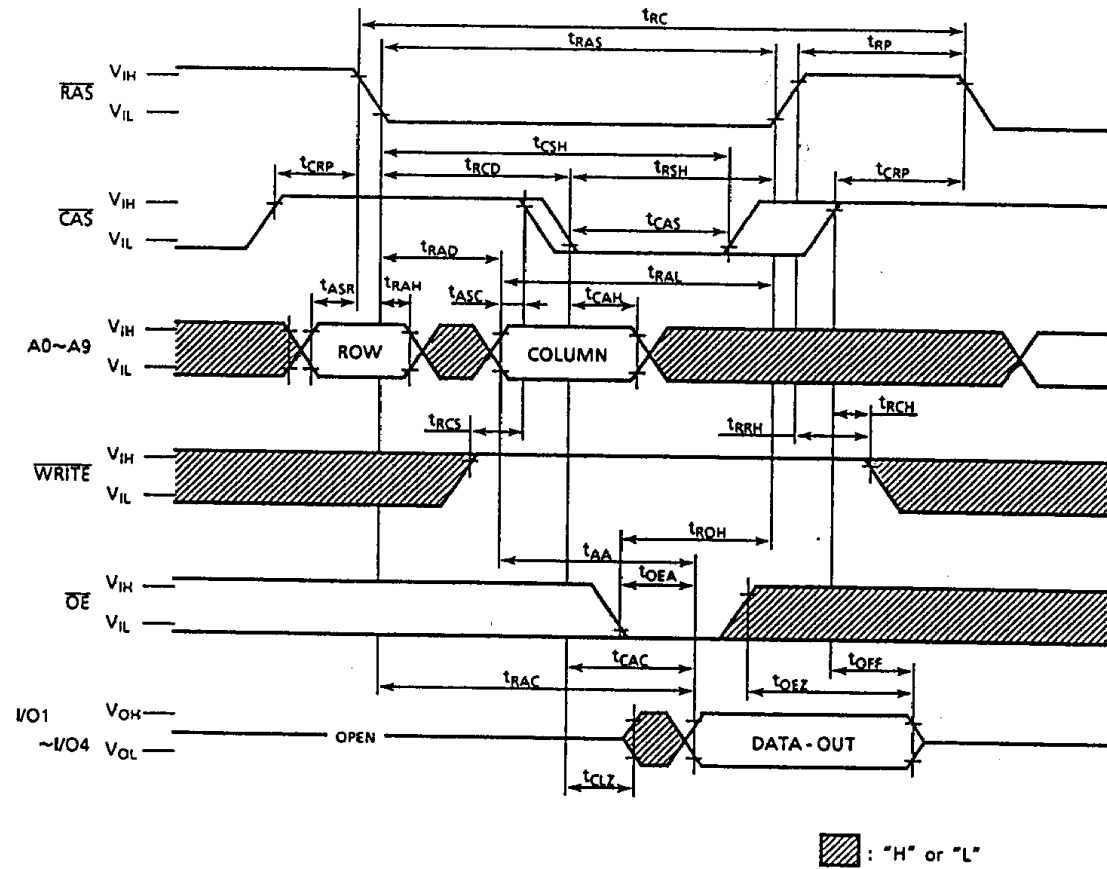
TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

NOTES:

1. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device.
2. All voltages are referenced to V_{SS} .
3. $ICC1$, $ICC3$, $ICC4$, $ICC6$, $ICC7$ depend on cycle rate.
4. $ICC1$, $ICC4$ depend on output loading. Specified values are obtained with the output open.
5. Column address can be changed once or less while $\overline{RAS}=V_{IL}$ and $\overline{CAS}=V_{IH}$.
6. $t_{RAS(max.)}=1\mu s$ is only applied to refresh of battery-back up. $t_{RAS(max.)}=10\mu s$ is applied to functional operating.
7. An initial pause of $200\mu s$ is required after power-up followed by 8 $\overline{RAS}$ only refresh cycles before proper device operation is achieved. In case of using internal refresh counter, a minimum of 8 $\overline{CAS}$ before $\overline{RAS}$ refresh cycles instead of 8 $\overline{RAS}$ only refresh cycles are required.
8. AC measurements assume $t_T=5ns$.
9. V_{IH} (min.) and V_{IL} (max.) are reference levels for measuring timing of input signals. Also, transition times are measured between V_{IH} and V_{IL} .
10. Measured with a load equivalent to 2 TTL loads and $100pF$.
11. $t_{OFF(max.)}$ and $t_{OEZ(max.)}$ define the time at which the output achieves the open circuit condition and are not referenced to output voltage levels.
12. Either t_{RCH} or t_{RRH} must be satisfied for a read cycle.
13. These parameters are referenced to $\overline{CAS}$ leading edge in early write cycles and to $\overline{WRITE}$ leading edge in Read-Modify-Write cycles.
14. t_{WCS} , t_{RWD} , t_{CWD} , t_{AWD} and t_{CPWD} are not restrictive operating parameters. They are included in the data sheet as electrical characteristics only. If $t_{WCS} \geq t_{WCS(min.)}$, the cycle is an early write cycle and the data out pin will remain open circuit (high impedance) through the entire cycle; If $t_{RWD} \geq t_{RWD(min.)}$, $t_{CWD} \geq t_{CWD(min.)}$, $t_{AWD} \geq t_{AWD(min.)}$ and $t_{CPWD} \geq t_{CPWD(min.)}$ (Fast Page Mode), the cycle is a Read-Modify-Write cycle and the data out will contain data read from the selected cell: If neither of the above sets of conditions is satisfied, the condition of the data out (at access time) is indeterminate.
15. Operation within the $t_{RCD(max.)}$ limit insures that $t_{RAC(max.)}$ can be met. $t_{RCD(max.)}$ is specified as a reference point only: If t_{RCD} is greater than the specified $t_{RCD(max.)}$ limit, then access time is controlled by t_{CAC} .
16. Operation within the $t_{RAD(max.)}$ limit insures that $t_{RAC(max.)}$ can be met. $t_{RAD(max.)}$ is specified as a reference point only: If t_{RAD} is greater than the specified $t_{RAD(max.)}$ limit, then access time is controlled by t_{AA} .

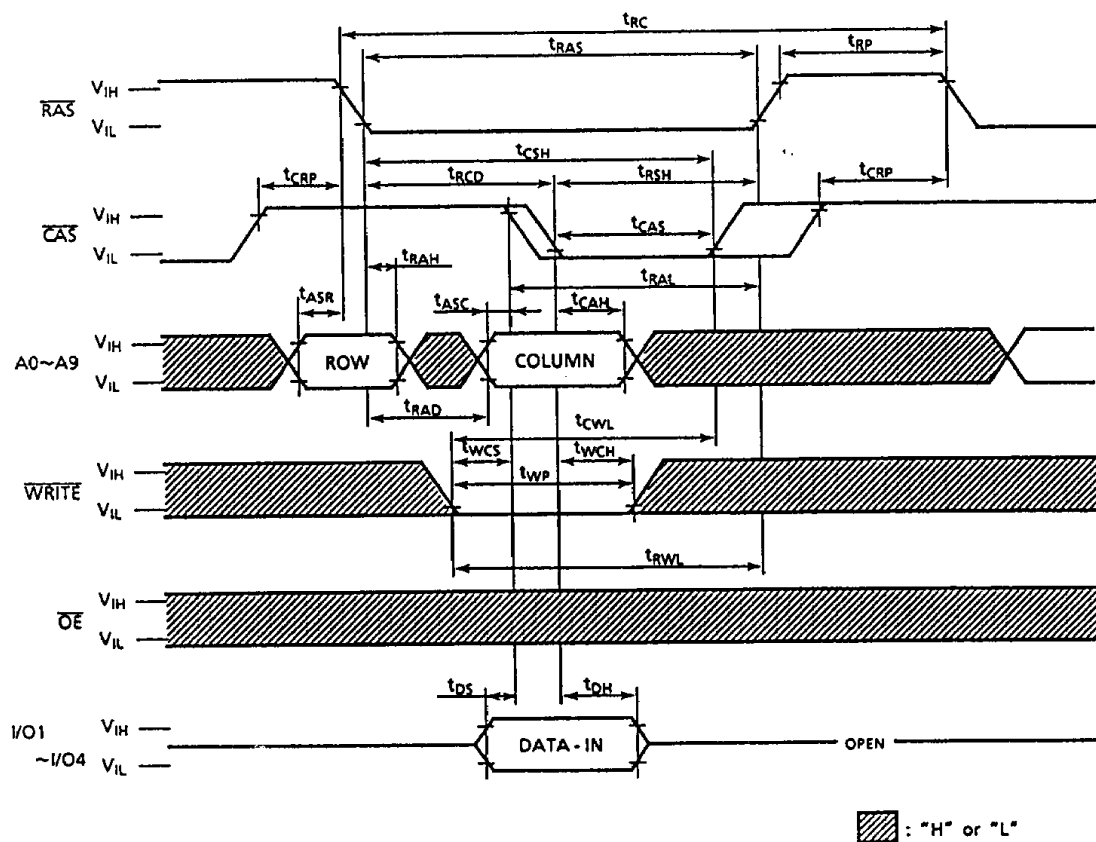
TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80
TC514400APL/AJL/ASJL/AZL-10

READ CYCLE



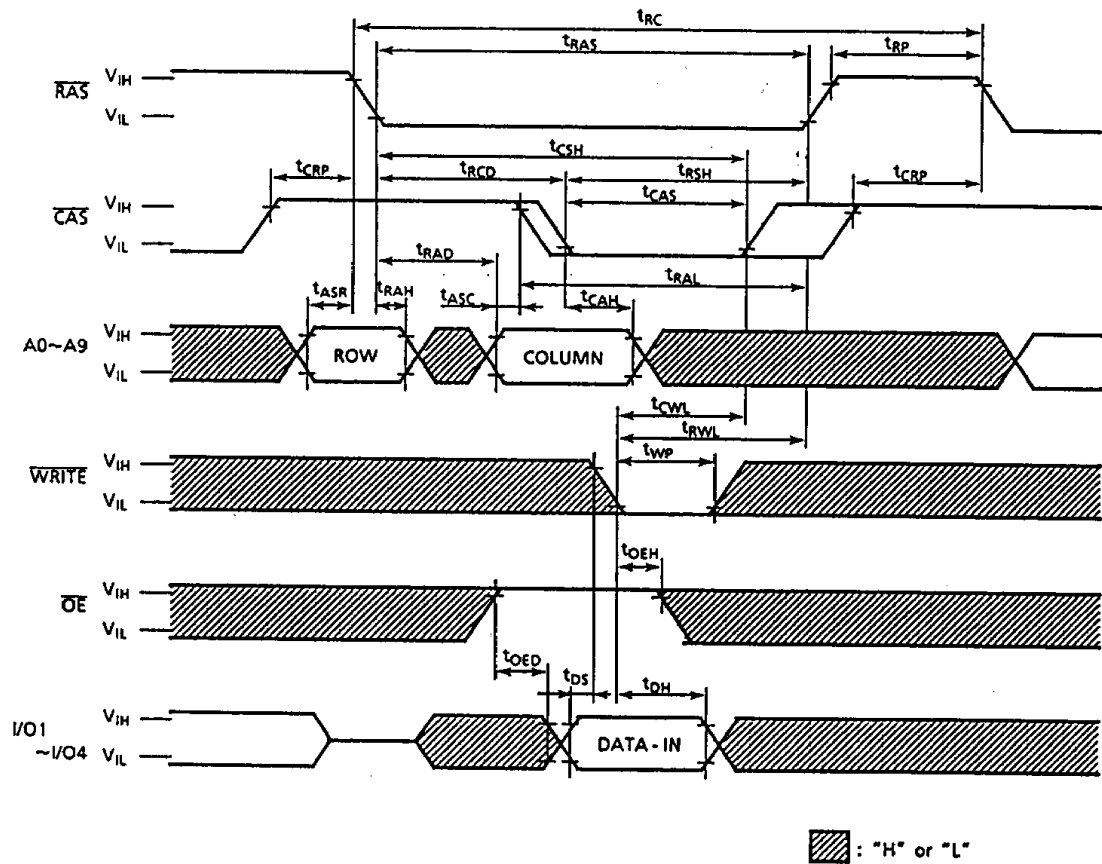
TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

WRITE CYCLE (EARLY WRITE)



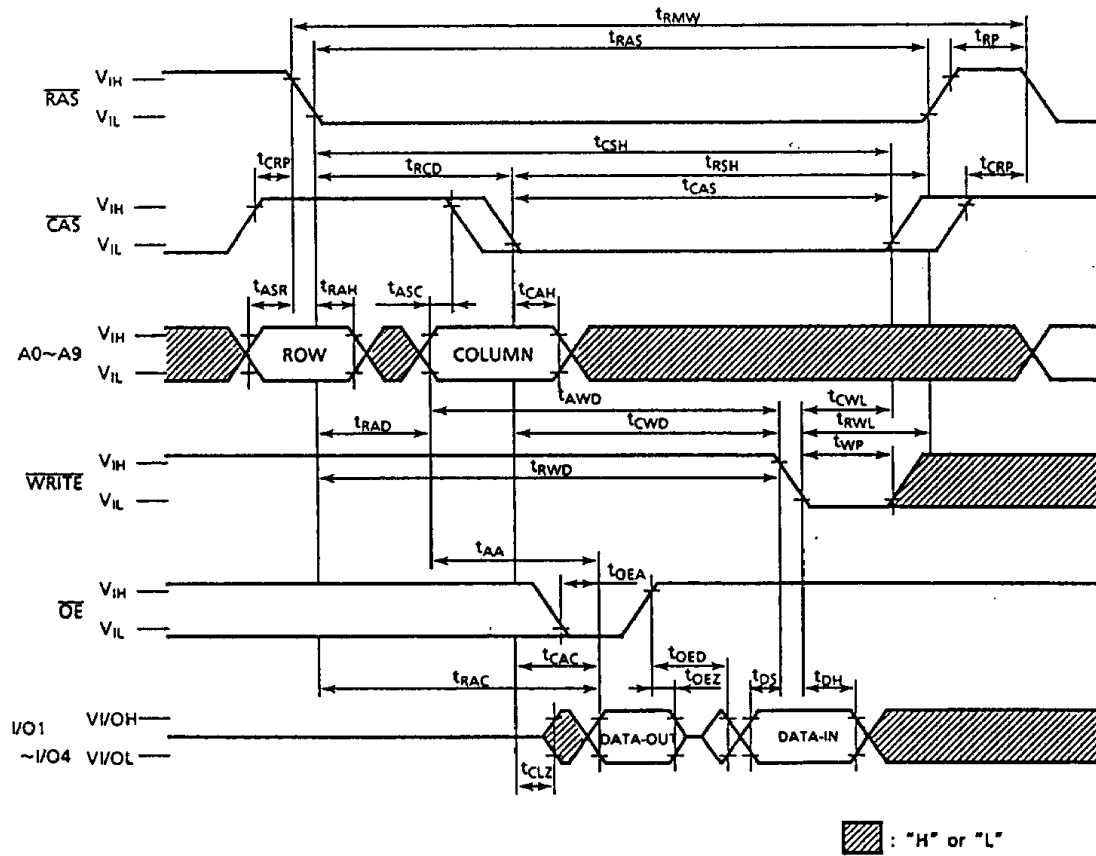
TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80
TC514400APL/AJL/ASJL/AZL-10

WRITE CYCLE ($\overline{OE}$ CONTROLLED WRITE)



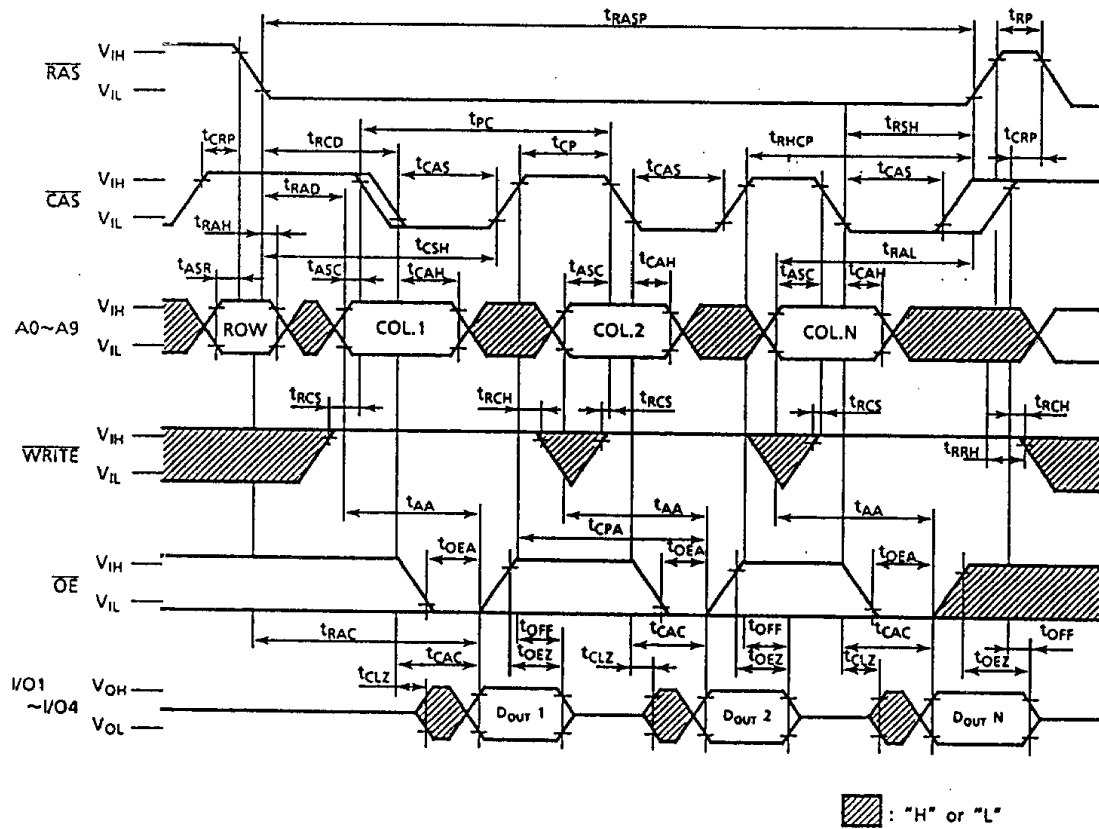
TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

READ-MODIFY-WRITE CYCLE



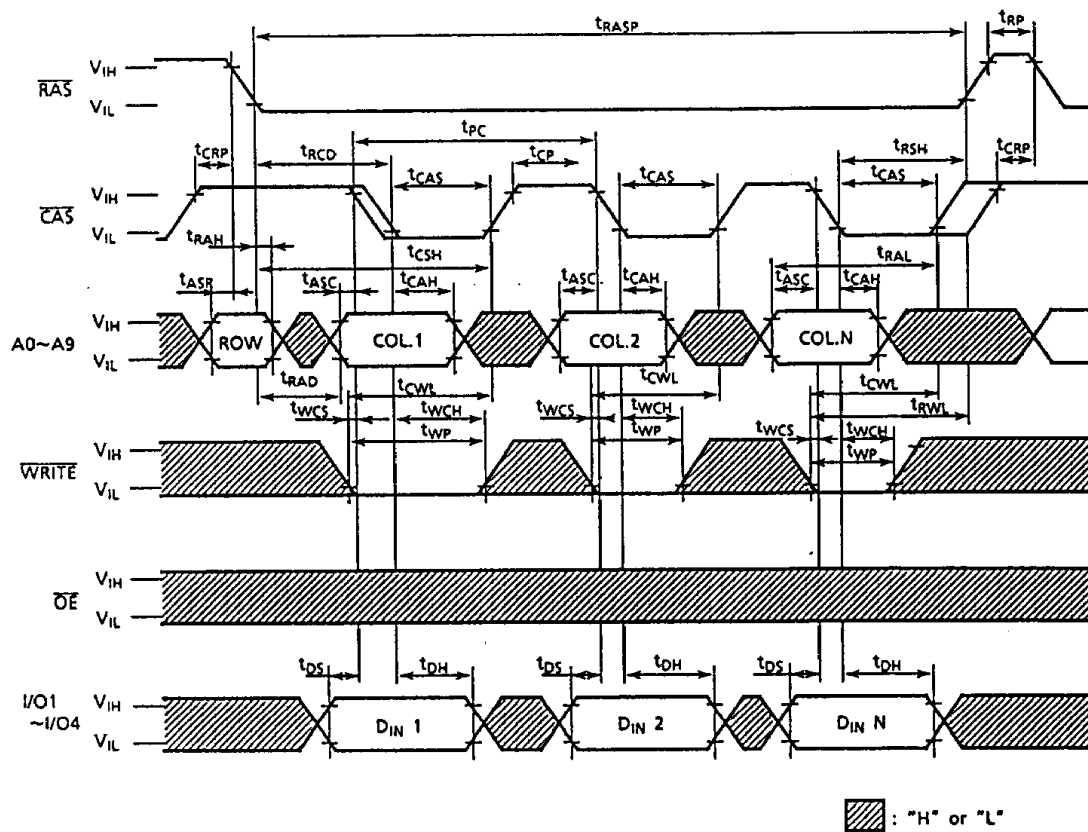
TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80
TC514400APL/AJL/ASJL/AZL-10

FAST PAGE MODE READ CYCLE



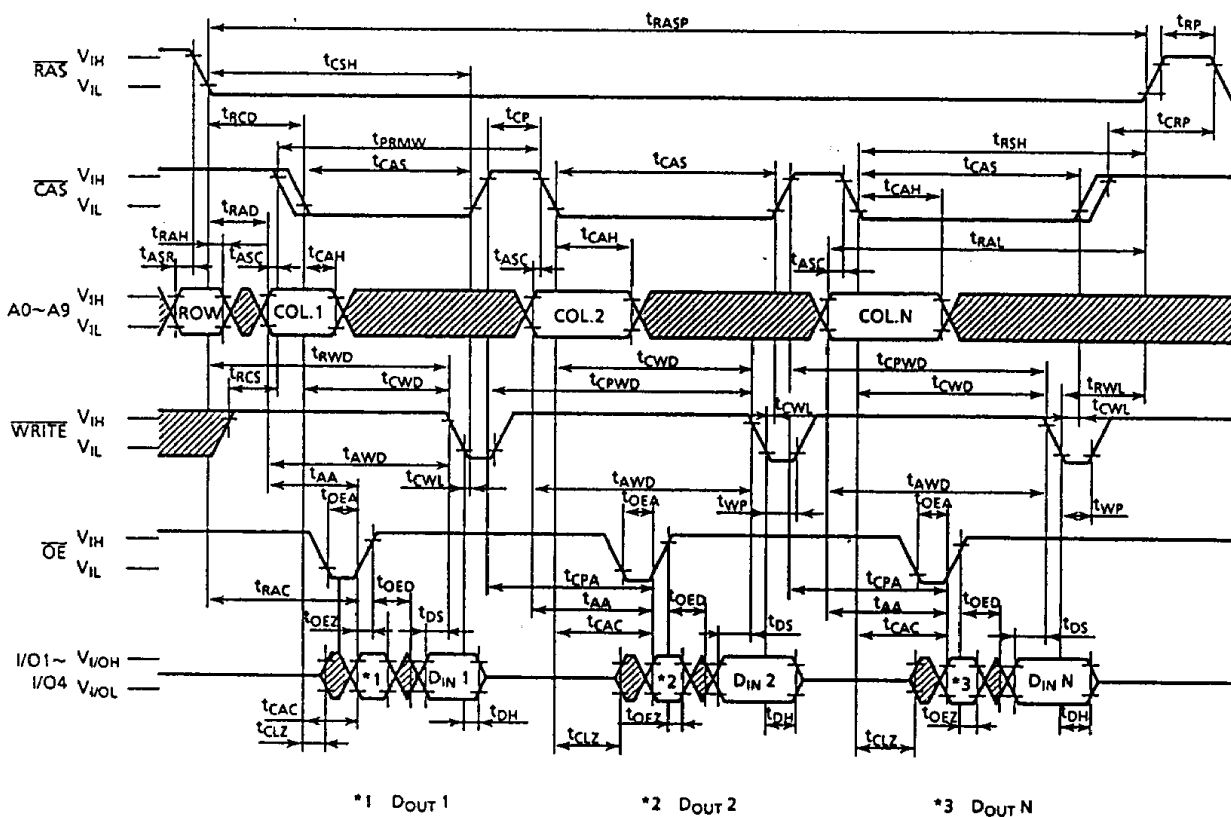
TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

FAST PAGE MODE WRITE CYCLE



TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

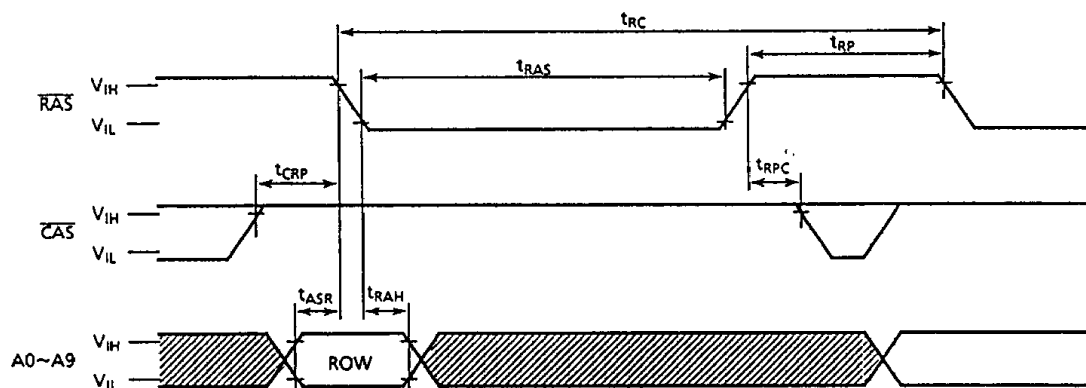
FAST PAGE MODE READ-MODIFY-WRITE CYCLE



▨ : "H" or "L"

TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

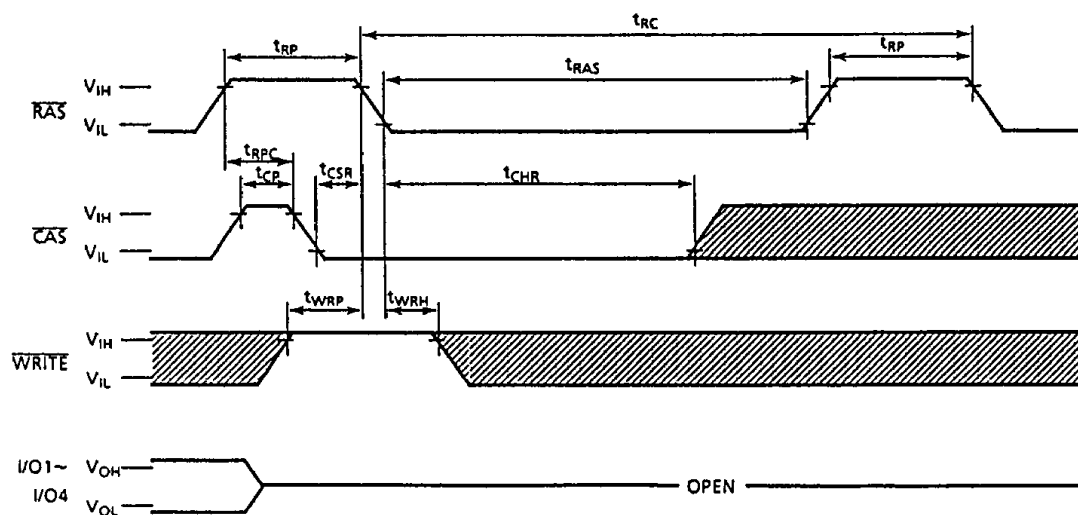
RAS ONLY REFRESH CYCLE



Note: $\overline{\text{WRITE}}$, $\overline{\text{OE}} = \text{"H"}$ or "L"

▨ : "H" or "L"

CAS BEFORE RAS REFRESH CYCLE

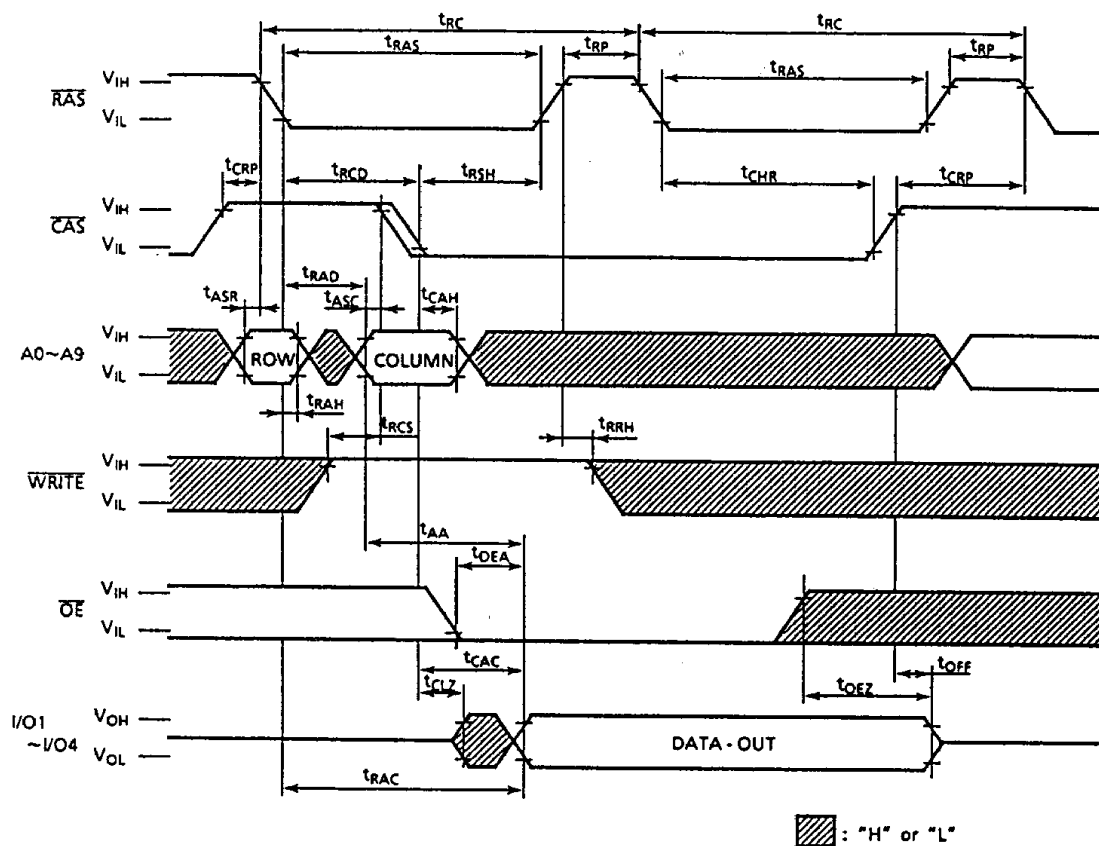


▨ : "H" or "L"

Note: $\overline{\text{OE}}$, $\text{A0} \sim \text{A9} = \text{"H"}$ or "L"

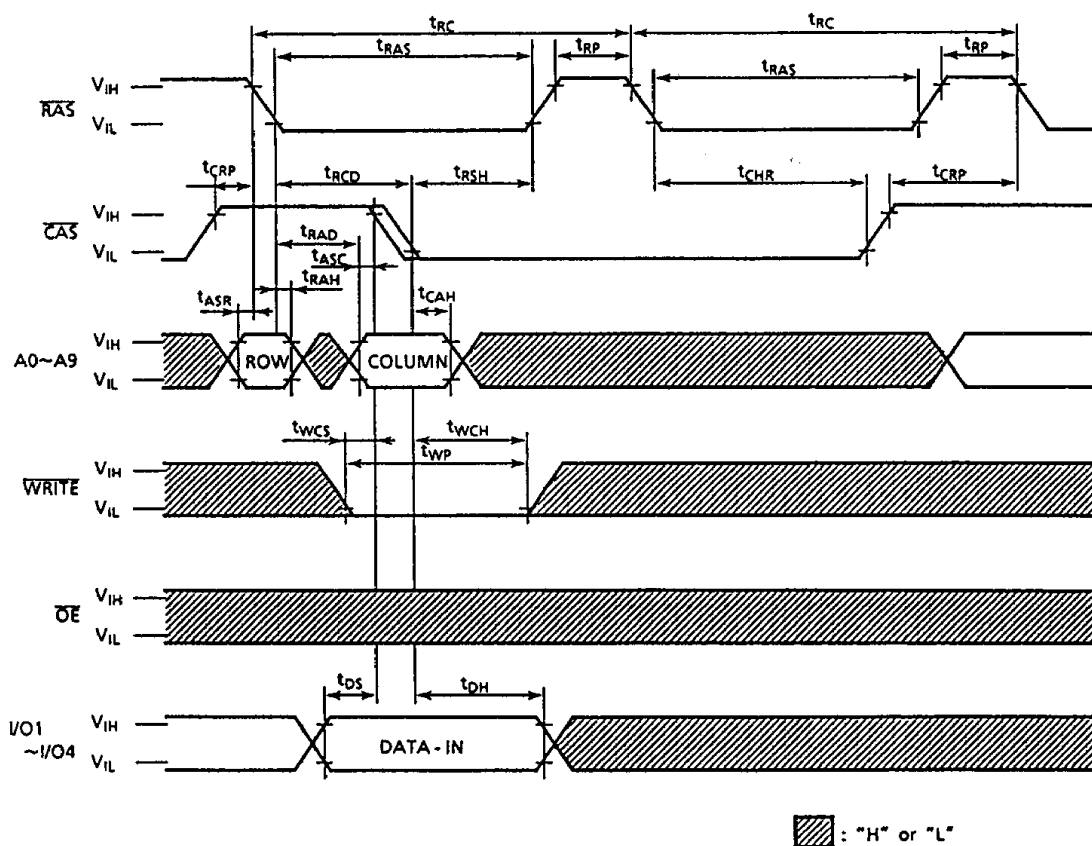
TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

HIDDEN REFRESH CYCLE (READ)



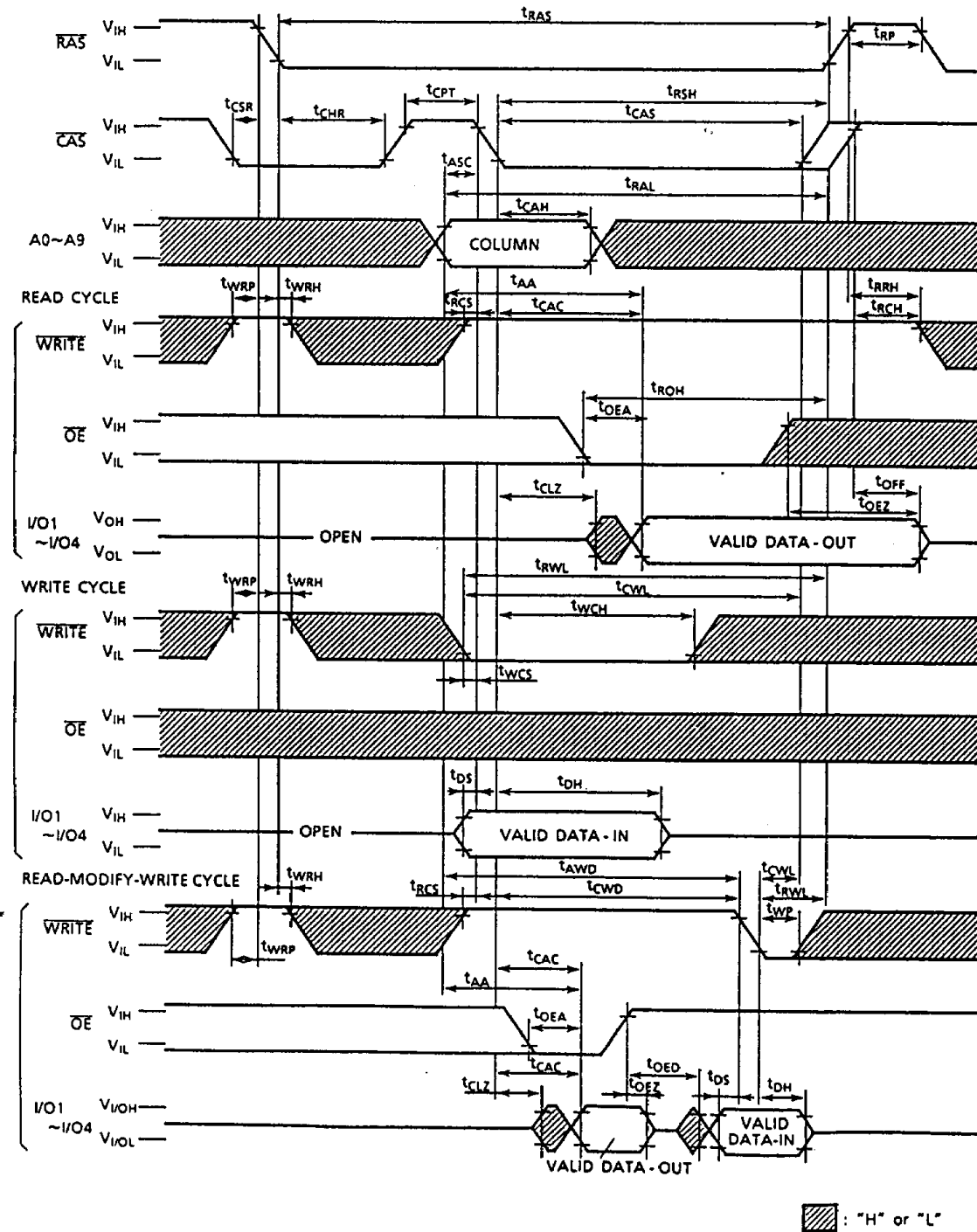
TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

HIDDEN REFRESH CYCLE (WRITE)



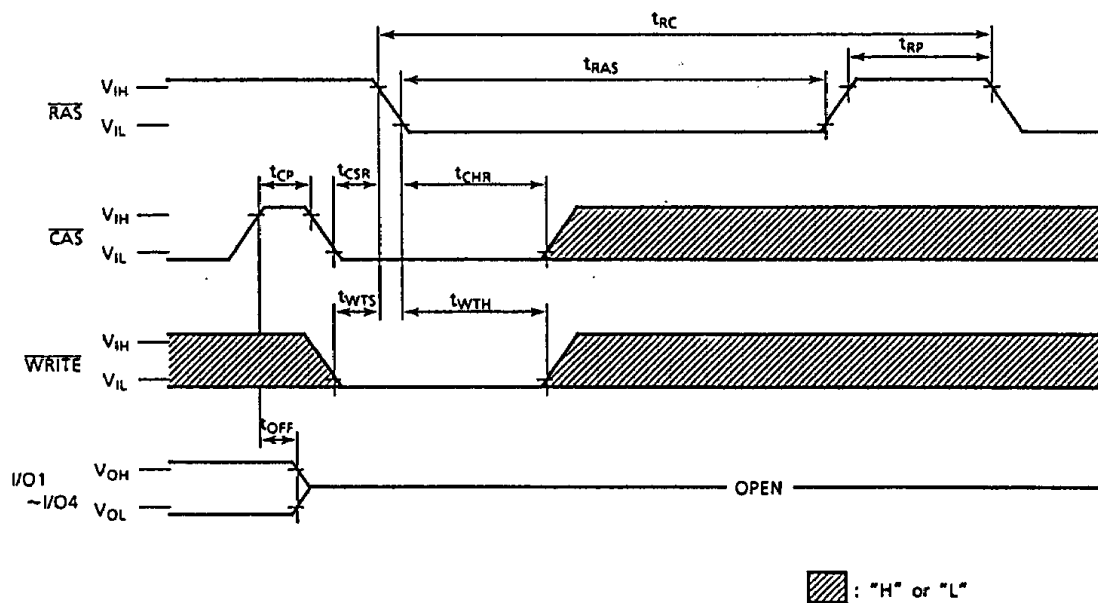
TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

CAS BEFORE RAS REFRESH COUNTER TEST CYCLE



TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

WRITE, $\overline{\text{CAS}}$ BEFORE $\overline{\text{RAS}}$ REFRESH CYCLE



Note: $\overline{\text{OE}}$, A0~A9: "H" or "L"

TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

TEST MODE

The TC514400APL/AJL/ASJL/AZL is the RAM organized 1,048,576 words by 4 bits, it is internally organized 524,288 words by 8 bits. In "Test Mode", data are written into 8 sectors in parallel and retrieved the same way. Aoc is not used. If, upon reading, two bits on one I/O pin are equal (all "1"s or "0"s), the I/O pin indicates a "1".

If they were not equal, the I/O pin would indicate a "0". Fig.1 shows the block diagram of TC514400APL/AJL/ASJL/AZL. In "Test Mode", the 1M×4 DRAM can be tested as if it were a 512K×4 DRAM.

"WRITE, CAS Before RAS Refresh Cycle" puts the device into "Test Mode". And "CAS Before RAS Refresh Cycle" or "RAS Only Refresh Cycle" puts it back into "Normal Mode". In the Test Mode, "WRITE, CAS Before RAS Refresh Cycle" Performs the refresh operation with the internal refresh address counter. The "Test Mode" function reduces test times (1/2 in case of N test pattern).

TC514400APL/AJL/ASJL/AZL-70, TC514400APL/AJL/ASJL/AZL-80 TC514400APL/AJL/ASJL/AZL-10

BLOCK DIAGRAM IN THE TEST MODE

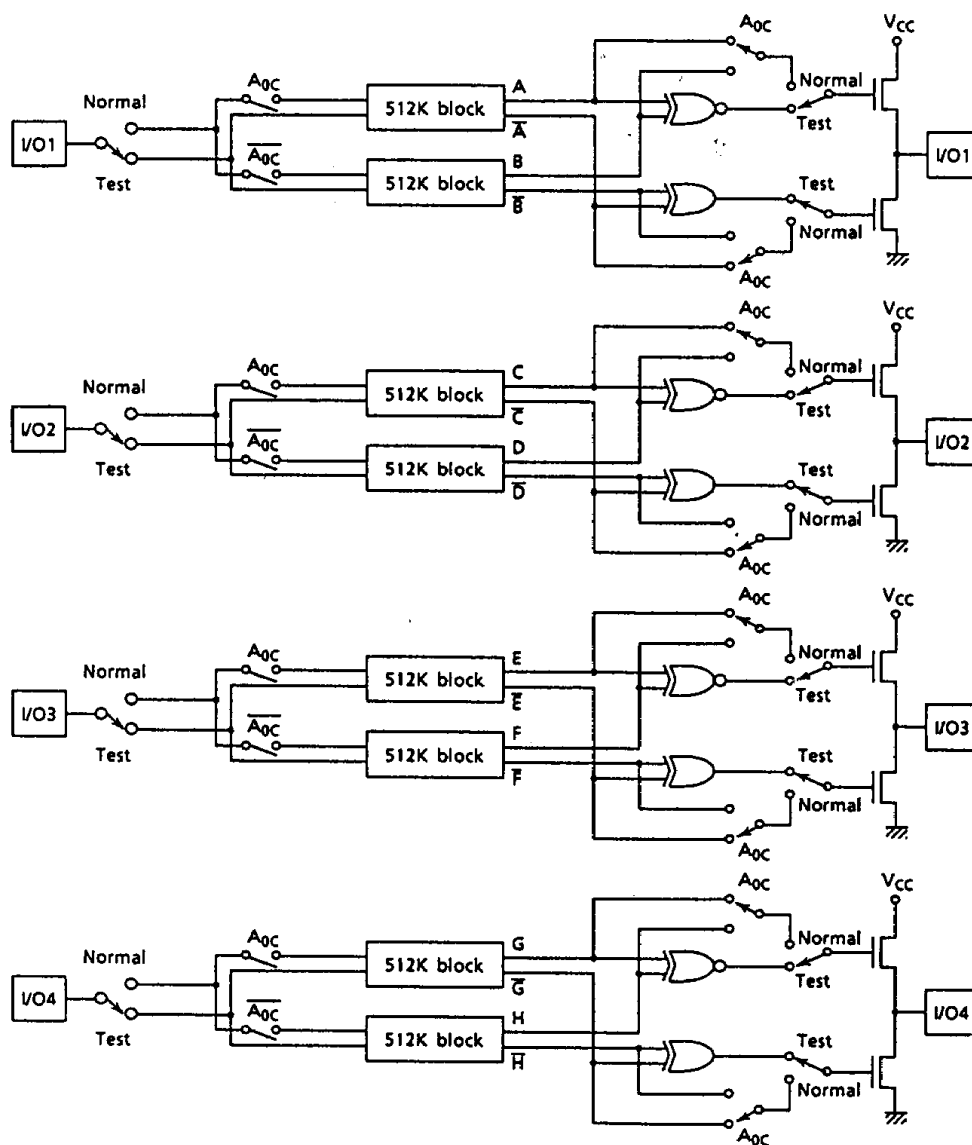


Fig. 1